



Docket No.: M4065.0658/P658  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

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In re Reissue Application of:  
Chandra Mouli et al.

Allowed: July 19, 2006

Application No.: 10/648,245

Confirmation No.: 3753

Filed: August 27, 2003

Art Unit: 2878

For: PHOTODIODE WITH ULTRA-  
SHALLOW JUNCTION FOR HIGH  
QUANTUM EFFICIENCY CMOS  
IMAGE SENSOR AND METHOD OF  
FORMATION

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Examiner: D. N. Monbleau

**COMMENTS ON STATEMENT OF REASONS  
FOR ALLOWANCE UNDER 37 C.F.R. §1.104(E)**

MS Issue Fee  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

Applicants have received the Examiner's Statement of Reasons for Allowance with the July 19, 2006 Notice of Allowance and Allowability regarding the above-identified application. Entry of the Statement into the record should not be construed as any agreement with or acquiescence in the reasoning stated by the Examiner. Each of the claims stands on its own merits and is patentable because of the combination it recites and not because of the presence or absence of any one particular element.

The Examiner's Statement was not prepared by Applicants and only contains the Examiner's possible positions in one or more reasons for allowability. Thus, any interpretation with respect to the Examiner's Statement of Reasons for Allowance should not be imputed to the Applicants.

Dated: August 22, 2006

Respectfully submitted,

By 

Thomas J. D'Amico

Registration No.: 28,371

Gabriela I. Coman

Registration No.: 50,515

DICKSTEIN SHAPIRO LLP

1825 Eye Street, NW

Washington, DC 20006-5403

(202) 420-2200

Attorneys for Applicant